NSN 5961-00-963-4987

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View Online at https://aerobasegroup.com/nsn/5961-00-963-4987 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.250 inches and 0.340 inches **Overall Height:** Between 0.250 inches and 0.340 inches Overall Width: 0.700 inches **Overall Diameter:** 0.500 inches **End Application:** Models hb, hn series **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 29.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life:

No

Unit Of Measure:

Demilitarization:

N/a

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